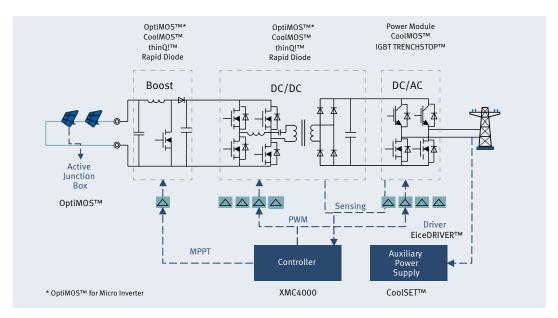


Infineon Solar Power Solutions

Infineon leading products for Complete Solar Power Solution



Infineon provides a comprehensive portfolio to deliver the best efficiency and reliability for solar applications. Infineon's leading edge technology like Superjunction MOSFET, Trench + Fieldstop IGBT, Coreless transformer driver, etc, combined with rich experience and highest quality, ensured our No.1 position in solar application. The newest add ARM® CortexTM-M4 based MCU enables easy and high efficiency design.

Solar power conversion has three distinctive requirements:

- System cost down: Inverters manufacturers will continuously optimize \$/w on system level.
- System efficiency: Efficiency is key for return of investment.
- Reliability: 5+years warranty for string inverters and 25 years for micro inverter and optimizer.

Infineon addresses above solar requirements with the best semiconductor solutions.

System cost down

- Increasing switching frequency enables cost reduction on magnetic, housing, cooling, etc.
 Infineon next generation CoolMOS™ C7 and IGBT TRENCHSTOP™5 provide high frequency possibility.
- Infineon CoolMOS™ P6 and TRENCHSTOP™5 offer superior price performance balance.

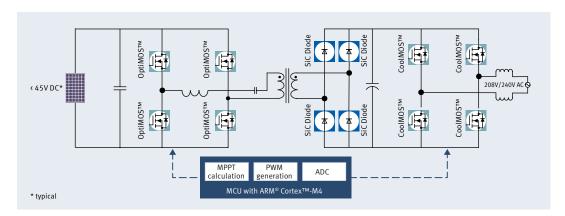
Efficiency

- Infineon CoolMOS™ C7 offers industry highest efficiency at hard switching, CoolMOS™ CFD2 and upcoming Infineon CoolMOS™ P6 offer optimized efficiency across whole load for soft switching.
- Infineon New OptiMOSTM has lowest $R_{DS(on)}$ in same package, 50% less gate drive charge than competitor, offers the highest efficiency across the whole load condition.

Reliability

- Infineon has long industry experience in Si & SiC devices and power module production with highest reliability record
- Infineon EiceDRIVER™ with coreless transformer technology offers isolation safety and stable life time performance
- Infineon PressFIT for highest contact reliability

Infineon Micro Inverter Solution



Micro inverter performs panel level DC-AC conversion, monitoring and communication to increase system efficiency and drive down system maintenance cost.

Infineon OptiMOS™ in SS08 package provides the highest power conversion efficiency and compact design, Infineon CoolMOS™ series provide highest efficiency and ThinPAK 8x8 offers compact design. Infineon Microcontroller has built-in high resolution PWM and high accuracy ADC, which enables precise digital control.

Infineon OptiMOS™ for Micro Inverter¹)

V_{in}	Topology	V _{ds}	OptiMOS™
Up to 48V	Half-Bridge	60V	BSC016N06NS
Up to 48V	Full-Bridge	60V	BSC028N06NS
Up to 64V	Full-Bridge	80V	BSC047N08NS3 G
Up to 60V	Flyback	150V	BSC190N15NS3 G

- Highest conduction efficiency in same package
- Highest switching efficiency with low gate charge
- Compact design and low EMI



Infineon CoolMOSTM for Micro Inverter 1)

Topology	Package	V _{ds}	CoolMOS™
Current Source	D²Pak	800V	SPB17N80C3
Current / Voltage	D ² PAK	650V	IPB65R190C6
Source	ThinPAK	600V	IPL60R210P6 ²⁾

- Highest efficiency with robust body diode
- Compact design and low EMI



Infineon thinQ!™ SiC Diode for Micro Inverter¹)

Topology	Package	V_{ds}	thinQ!™
Rectification	DPAK	600V	IDD05SG60C

Zero reverse recovery charge

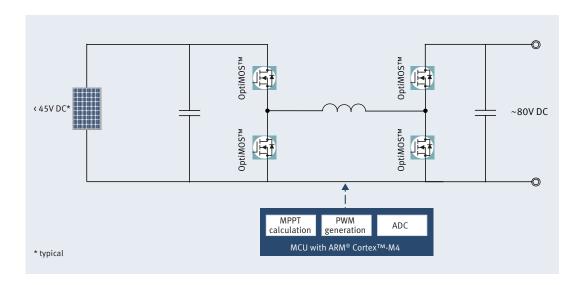
InfineonXMC4000 for Maximum Power Point Tracking and PWM control

- ARM® CortexTM-M4 with floating point unit (FPU), single-cycle DSP MAC, 80-120 MHz CPU frequency
- 4-channel high-resolution, PWM (150 ps) (XMC4400, XMC4200, XMC4100)
- Up to 4x 12-bit ADC achieving 4 Mega samples per second (interleaved mode)
- DAVE3TM Free Development Platform

¹⁾ Most common used part numbers. Other voltage / current rating/ package available at www.lnfineon.com/optimos www.lnfineon.com/coolmos www.lnfineon.com/sic

²⁾ Available in Q4 2013

Infineon Optimizer Solution



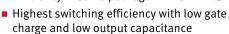
Optimizer performs panel level maximum power point tracking, monitoring and communication to increase system efficiency and drive down system maintenance cost.

Infineon OptiMOS™ in SS08 package for optimizer and DrMOS for nano optimizer provide the highest power conversion efficiency and compact design, ARM® Cortex™-M4 based XMC4000 series of Microcontroller provides high resolution PWM control and high accuracy integrated ADC.

Infineon OptiMOS™ for Optimizer DC-DC Power Conversion ¹)

V_{in}	Topology	V_{ds}	OptiMOS™
up to 48V	Buck-Boost	60V	BSC028N06NS
up to 60V		75V	BSC042NE7NS3 G
up to 64V		80V	BSC047N08NS3 G
			BSC057N08NS3 G
up to 80V		100V	BSC060N10NS3 G

 Highest conduction efficiency in same package

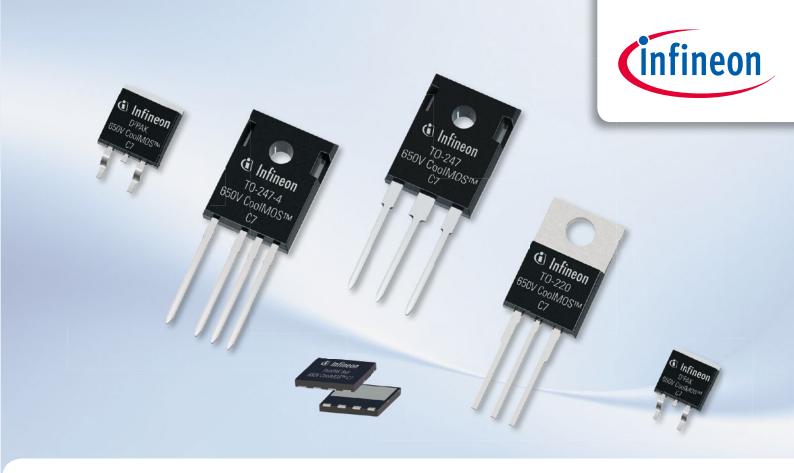


Compact design and low EMI

InfineonXMC4000 for Maximum Power Point Tracking and PWM control

- ARM® CortexTM-M4 with floating point unit (FPU), single-cycle DSP MAC, 80-120 MHz CPU frequency
- 4-channel high-resolution, PWM (150 ps) (XMC4400, XMC4200, XMC4100)
- Up to 4x 12-bit ADC achieving 4 Mega samples per second (interleaved mode)
- DAVE3[™] Free Development Platform

¹⁾ Most common used part numbers. Other voltage / current rating/ package available at www.lnfineon.com/optimos



650V CoolMOS™ C7

Get in Touch with World Leading Performance



Infineon's new CoolMOSTM C7 series is a revolutionary step forward in technology, providing the world's lowest $R_{DS(on)}/package$ to hard switching applications. The fast switching performance of C7 now enables switching frequencies greater than 100kHz whilst achieving titanium levels of efficiency in Server PFC stages. This opens new ways for higher power density.



Key features and benefits of new 650V CoolMOS™ C7

- Increased power density due to higher frequency operation
- Revolutionary Best-in-Class R_{DS(on)}/package
 - Enabling the world's lowest $R_{DS(on)}$ of $19m\Omega$ in a TO-247 and $45m\Omega$ in TO-220 and D^2PAK



- \blacksquare Low switching and conduction losses (improved $\textbf{Q}_{\text{g}},\,\textbf{E}_{\text{oss}},\,\textbf{Q}_{\text{oss}})$
 - Leads to Efficiency improvements over full load range
- 650V makes it suitable for both SMPS and Solar









For further information please visit our website: www.infineon.com/c7



Infineon Solar Solution Selection Tree

Showing only solar dedicated devices. For complete po

Optimizer

OptiMOS™ SS08/CanPAK | 75V - 150\

MOSFET

SiC Diode

IGBT

Fast Si Diode

Power Module & Stack

Driver

Schottky Diode

Auxiliary Power Supply

Micro Controller

MCU: XMC4100/4200

ortfolio, check www.infineon.com

	Micro Inverter 200W - 300W	Stri 1
V	OptiMOS™ CoolMOS™ SS08 60V-200V D²PAK/ThinPAK 600V-800V	TO247 600
	thinQ!™ ThinPAK/DPAK 650V/1200V	TO-220/TO
		Rap
		EasyPAC
	MCU: XMC4100/4200	MCU: XN



ng Inverter kW - 30kW

Central Inverter 30kW - 500kW

oolMOS™ 0/650V | 19mΩ-99mΩ

thinQ!™ -247 | 650V/1200V

TRENCHSTOP™5/TRENCHSTOP™/HighSpeed 3 600V/650V/1200V | TO-247 Single/DuoPack

oid Diode 1/2 TO247

K 1B/2B Press FIT

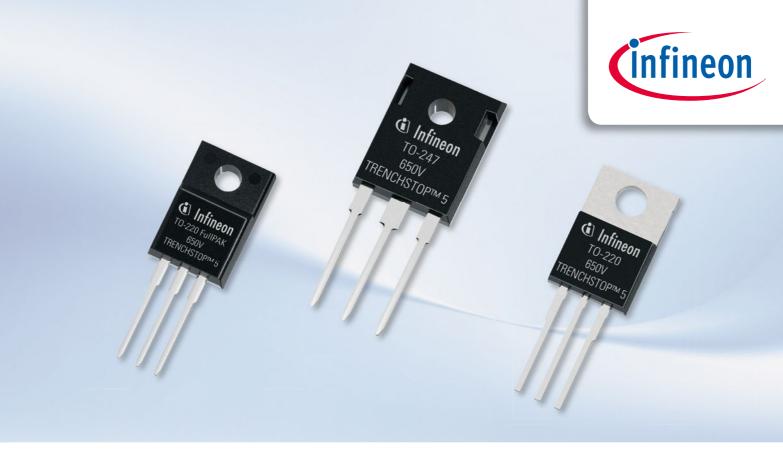
PrimePACK™/PrimeSTACK™/IHM-B EconoPACK™ 4/EconoDUAL™ 3,62mm

IGBT Driver: 1ED020l12-F2, 2ED020l12-F2

BAT165 Schottky Diode

CoolSET™ 800V

MC4400-XMC4500 MCU: XMC4700



650V TRENCHSTOP™5

Introducing a Technology to Match Tomorrow's High Efficiency Demands







The new TRENCHSTOP™5 IGBT technology from Infineon redefines the "Best-in-Class IGBT" by providing unmatched performance in terms of efficiency. When high efficiency, lower system costs and increased reliability are demanded, TRENCHSTOP™5 is the only option. The new TRENCHSTOP™5 IGBTs deliver a dramatic reduction in switching and conduction losses – for example in application measurement 1.7% efficiency improvement – whilst also offering a 650V breakthrough voltage. Can you afford to wait for the competition to catch up?

Key features and benefits of the brand new 650V TRENCHSTOP™5 IGBT technology

- New benchmark in terms of Best-in-Class efficiency
- Lowest ever switching losses
- V_{CE(sat)} more than 10% lower than previous generation
- 650V breakthrough voltage
- Temperature stable V_f value of Infineon's free-wheeling Rapid diode
- 2.5 factor lower Q_g compared to HighSpeed 3





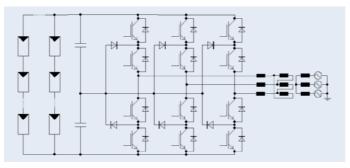


For further information please visit our website: www.infineon.com/trenchstop5



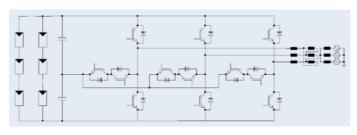
Infineon Central Inverter Solution

Infineon provides modules and stacks for central inverters from several tenth of kVA up to MVA of output power. These include a broad portfolio of different packages with the relevant voltage classes, current ratings and topologies. Infineon's modules and stacks are designed to cope with the requirements regarding reliability and efficiency.¹⁾





Sales Name	Sales Product Number	Package	Description
F3L200R07PE4	SP000711886	EconoPACK™ 4	3-Level NPC1, 650V, 200A
F3L300R07PE4	SP000711882	EconoPACK™ 4	3-Level NPC1, 650V, 300A
F3L400R07ME4_B22	SP000893966	EconoDUAL™ 3	Upper half of NPC1, 650V, 400A
F3L400R07ME4_B23	SP000893970	EconoDUAL™ 3	Lower half of NPC1, 650V, 400A
F3L300R12ME4_B22	SP000931254	EconoDUAL™ 3	Upper half of NPC1, 1200V, 300A
F3L300R12ME4_B23	SP000931258	EconoDUAL™ 3	Lower half of NPC1, 1200V, 300A

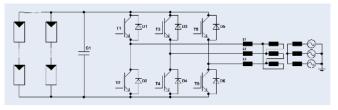




Sales Name	Sales Product Number	Package	Description
FF200R12KE4	SP000370604	62mm	Half-Bridge, 1200V, 200A
FF300R12KE4	SP000370620	62mm	Half-Bridge, 1200V, 300A
FF450R12KE4	SP000370610	62mm	Half-Bridge, 1200V, 450A
FF200R17KE4	SP000713374	62mm	Half-Bridge, 1700V, 200A
FF300R17KE4	SP000713528	62mm	Half-Bridge, 1700V, 300A
FF200R12KT3_E	SP000251629	62mm	Neutral branch of NPC2, 1200V, 200A
FF300R12KT3_E	SP000357408	62mm	Neutral branch of NPC2, 1200V, 300A
FF400R12KT3_E	SP000314729	62mm	Neutral branch of NPC2, 1200V, 400A
F3L400R07PE4_B26	SP000929978	EconoPACK™ 4	3-Level NPC2, 650V, 400A
F3L300R12PT4_B26	SP000929996	EconoPACK™ 4	3-Level NPC2, 1200V, 300A
F3L400R12PT4_B26	SP000929974	EconoPACK™ 4	3-Level NPC2, 1200V, 400A

 $^{^{1)}}$ For complete portfolio, check www.infineon.com/powermodules

Infineon Central Inverter Solution



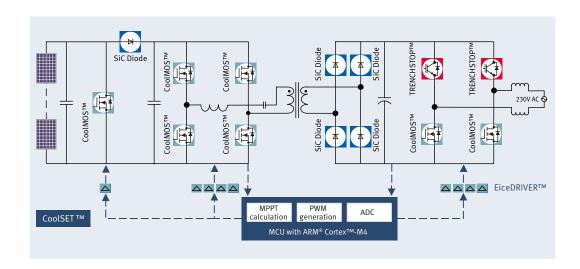


Sales Name	Sales Product Number	Package	Description
FF450R12IE4	SP000609746	PrimePACK™2	Half-Bridge, 1200V, 450A
FF600R12IE4	SP000614706	PrimePACK™2	Half-Bridge, 1200V, 600A
FF600R12IP4	SP000609754	PrimePACK™2	Half-Bridge, 1200V, 600A
FF900R12IE4	SP000614712	PrimePACK™2	Half-Bridge, 1200V, 900A
FF900R12IP4	SP000609750	PrimePACK™2	Half-Bridge, 1200V, 900A
FF1400R12IP4	SP000609758	PrimePACK™2	Half-Bridge, 1200V, 1400A
FF450R17IE4	SP000609596	PrimePACK™2	Half-Bridge, 1700V, 450A
FF650R17IE4	SP000614664	PrimePACK™2	Half-Bridge, 1700V, 650A
FF1000R17IE4	SP000609592	PrimePACK™2	Half-Bridge, 1700V, 1000A
FF1400R17IP4	SP000726974	PrimePACK™2	Half-Bridge, 1700V, 1400A
FZ1200R12HE4	SP000989586	IHM-B	Single-Switch, 1200V, 1200A
FZ1600R12HP4	SP000989532	IHM-B	Single-Switch, 1200V, 1600A
FZ2400R12HP4	SP000989472	IHM-B	Single-Switch, 1200V, 2400A
FZ3600R17HP4_B2	SP000478036	IHM-B	Single-Switch, 1700V, 3600A



Sales Name	Sales Product Number	Package	Description
2PS12012E33G27261	SP000235457	PS C3 air	Single phase stack, 1200V, 1200A
2PS18012E44G34421	SP000951714	PS C3 air	Single phase stack, 1200V, 1800A
2PS18012E44G37090	SP000957326	PS C3 air	Single phase stack, 1200V, 1800A
2PS18012E44G37576	SP000992676	PS C3 air	Single phase stack, 1200V, 1800A, cap box
2PS18012E44F34383	SP000763336	PS C3 air	Single phase stack, 1200V, 1800A, cap box, fan
2LS20017E42W36702	SP000934308	MS_C liquid	Single phase stack, 1700V, 2000A
6PS03012E33G34160	SP000724336	PS C3 air	3 phase inverter, 1200V, 300A, cap box
6PS04512E43G36013	SP000901000	PS C3 air	3 phase inverter, 1200V, 450A
6PS04512E43W38482	SP001059448	PS C3 liquid	3 phase inverter, 1200V, 450A
6PS09012E4DG35566	SP000878514	PS CD air	3 phase inverter, 1200V, 900A, cap box
6PS18012E4FG34676	SP000796402	PS CF air	3 phase inverter, 1200V, 1800A, cap box
6PS18012E4FG35689	SP000885246	PS CF air	3 phase inverter, 1200V, 1800A, cap box, fan

Infineon String Inverter Solution



Infineon Discrete Power Device for String Inverter 1)

Inverter Type	Function	Product Series	Typical part number	
	Boost	CoolMOS™ CP/C7	IPW65R045C7	
	BOOSt	thinQ!™ SiC Diode	IDW20G65C5	
		CoolMOS™ C6	IPW65R041C6	■ Hig
oinala mhaca	DC-DC	thinQ!™ SiC Diode	IDW20G65C5	cor
single phase		Rapid Diode	IDW15E65D2	Coi
	Inverter	TRENCHSTOP™	IKW50N60T	po pe
		TRENCHSTOP™ 5	IKW40N65H5	cos
		CoolMOS™ C6	IPW65R041C6	■ Hig
	Deast	TRENCHSTOP™	IKW40N120H3	
three phase	Boost	thinQ!™ SiC Diode	IDW30S120	
	Inverter	TRENCHSTOP™	IKW40N120H3	

High efficiency power conversion

- Complete product portfolio for high performance and system cost optimization
- High reliability

Infineon EiceDRIVER™ for String Inverter ¹)

Power Device	Driving Method	Voltage class	Typical part number	•
IGBT	Single channel	1200V	1ED020I12-F2/B2	
IGBT	Half Bridge	1200V	2ED020l12-Fl	

- Enables high efficiency design
- Coreless transformer technology offers longer lifetime reliability

Infineon CoolSETTM for String Inverter¹⁾

V_{ds}	Typical part number	_ 1
800V	ICE3AR2280JZ	Lowest standby consumption
650V	ICE3BR1765JZ	consumption

¹⁾ Most common used part numbers. Other voltage / current rating/ package available at www.infineon.com/coolmos www.infineon.com/sic www.infineon.com/igbt www.infineon.com/eicedriver www.infineon.com/coolset

Infineon String Inverter Solution

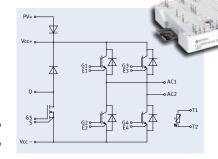
Single-phase Photo-voltaic Inverter Modules 1)

An entire PV inverter can be realized by using a single Easy 2B module. The modules incorporate an H-bridge as well as a booster and a bypass diode. These modules are applicable for PV Inverters with:

- High max. DC voltages, as 650 V chips are used
- Wide input voltage range, as booster is included
- Efficiency: approx. 97 %

- Reactive power capability
- Excellent price performance ratio
- Single standard topology
- 650V IGBTs / Diodes / MOSFET / SiC Schottky Diode

Sales Name	Sales Product Number	Package	Description		
F4-50R07W2H3_B51	SP000908430	Easy2B PressFIT	Integrated Booster / Inverter Module (1–4 kVA)		
F4-75R07W2H3_B51	SP000908422	Easy2B PressFIT	Integrated Booster / Inverter Module (3–8 kVA)]	





Three-phase Photo-voltaic Inverter Modules 1)

Booster modules and inverter modules are available. These modules are applicable for PV Inverters with:

- Max. DC Input Voltage: 1.000 V
- Max. Efficiency: 98 % + x
- Output power up to: 25 kVA

Inverter Modules

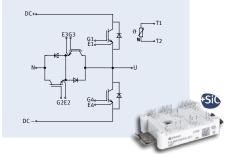
Advantages:

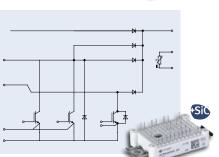
- Excellent efficiency and performance
- Full reactive power capability of PV inverter is supported
- Fully integrated module for 3-phase applications up to 9 kVA
- Phase leg module for applications up to 25 kVA

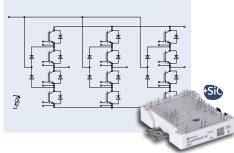
Booster Modules

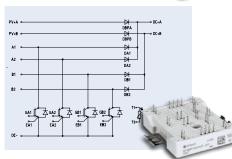
Advantages:

- 3 module types with SiC diodes available (F version)
- Up to four MPP-Trackers possible using one module









Sales Na	me	Sales Product Number	Package	Pin	Description	
	FS3L30R07W2H3F_B11	SP000944592	Easy 2B PressFIT	PressFIT	Inverter Module (7 kVA)	ŧSi
Inverter Modules	FS3L50R07W2H3F_B11	SP000944582	Easy 2B PressFIT	PressFIT	Inverter Module (9 kVA)	+Si
Modules	F3L80R12W1H3_B11	SP000908418	Easy 1B PressFIT	PressFIT	Inverter Phase Leg Module (25 kVA)	Si
	DF75R12W1H4F_B11	SP001080544	Easy 1B PressFIT	PressFIT	Booster Module (10 kVA fast)	+Si
	DF80R12W2H3_B11	SP000948772	Easy 2B PressFIT	PressFIT	Booster Module (10 kVA)	
Booster Modules	DF80R12W2H3F_B11	SP000908732	Easy 2B PressFIT	PressFIT	Booster Module (10 kVA fast)	Si
Modules	DF160R12W2H3_B11	SP000944548	Easy 2B PressFIT	PressFIT	Booster Module (20 kVA)	
	DF160R12W2H3F_B11	SP000908738	Easy 2B PressFIT	PressFIT	Booster Module (20 kVA fast)	Si

 $^{^{\}mathrm{1})}$ for complete portfolio, check www.infineon.com/string

Ask Infineon. Get connected with the answers.

Where you need it. When you need it.

Infineon offers its toll-free 0800/4001 service hotline as one central number, available 24/7 in English, Mandarin and German.

Our global connection service goes way beyond standard switchboard services by offering qualified support on the phone. Call us!

- Germany 0800 951 951 951 (German/English)
- China, mainland 4001 200 951 (Mandarin/English)
- India 000 800 4402 951 (English)
- USA 1-866 951 9519 (English/German)
- Other countries 00* 800 951 951 951 (English/German)
- Direct access+49 89 234-0 (interconnection fee, German/English)

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Published by Infineon Technologies Austria AG 9500 Villach, Austria

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Order Number: B152-H9805-X-X-7600-DB2012-0020 Date: 04 / 2013

^{*} Please note: Some countries may require you to dial a code other than "00" to access this international number, please visit www.infineon.com/service for your country!